

Radar Pulsed Power Transistor 115W, 2.7-2.9 GHz, 200µs Pulse, 10% Duty

M/A-COM Products PRELIMINARY, 10 Aug 07

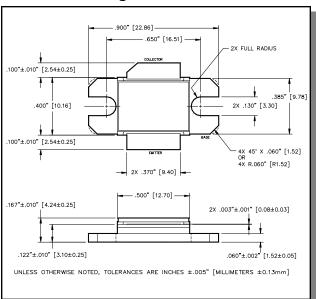
Features

- · NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant
- Device marked as PR2731-115M

Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	65	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current (Peak)	Ic	TBD	Α
Power Dissipation @ +25°C	P _{TOT}	TBD	W
Storage Temperature	T_{STG}	-65 to +200	°C
Junction Temperature	T_J	200	°C

Outline Drawing



Electrical Specifications: $T_C = 25 \pm 5^{\circ}C$ (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I _C = 40mA		BV _{CES}	65	-	V
Collector-Emitter Leakage Current	V _{CE} = 36V		I _{CES}	-	7.5	mA
Thermal Resistance	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	R _{TH(JC)}	-	TBD	°C/W
Output Power	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	P _{OUT}	115	-	W
Power Gain	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	G _P	7.6	-	dB
Gain Flatness	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	ΔG	-	1.0	dB
Collector Efficiency	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	ης	38	-	%
Pulse Droop	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	Droop	-	0.5	dB
Input Return Loss	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	RL	-	-10	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	VSWR-T	-	2:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 20W	F = 2.7, 2.9, 3.1 GHz	VSWR-S	-	1.5:1	-

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 Visit www.macomtech.com for additional data sheets and product information.

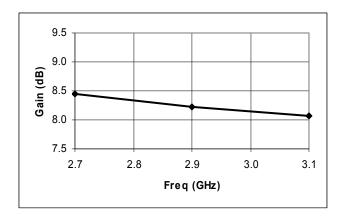


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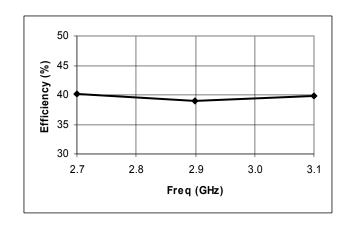
Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	ΔGain (dB)	Ic (A)	Eff (%)	RL (dB)	Droop (dB)	VSWR-S (1.5:1)	VSWR-T (2:1)
2.7	20	140	8.45	-	9.16	40.1	-11.8	0.00	S	Р
2.9	20	133	8.23	-	8.97	38.9	-16.6	0.12	S	Р
3.1	20	128	8.06	0.39	8.49	39.8	-15.3	0.26	S	Р

Gain vs. Frequency



Collector Efficiency vs. Frequency

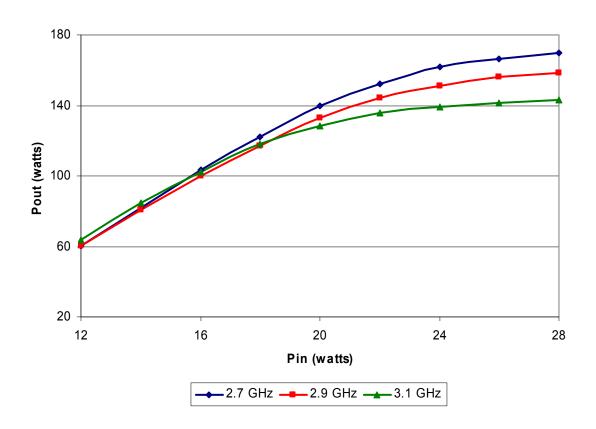


typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.



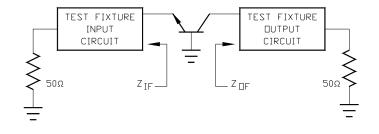
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RF Power Transfer Curve (Output Power Vs. Input Power)



RF Test Fixture Impedance

F (GHz)	Z _{IF} (Ω)	Z _{OF} (Ω)		
2.7	4.7 - j6.1	2.4 - j2.4		
2.8	4.5 - j5.8	2.4 - j2.2		
2.9	4.4 - j5.7	2.4 - j2.0		
3.0	4.3 - j5.5	2.4 - j1.8		
3.1	4.1 - j5.3	2.4 - j1.6		



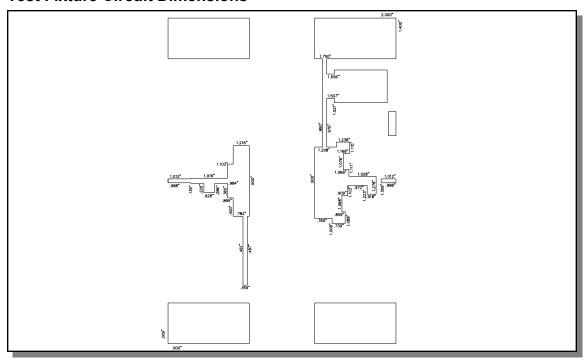
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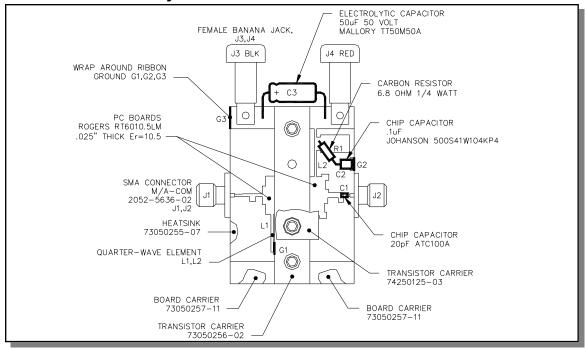


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Test Fixture Circuit Dimensions



Test Fixture Assembly



and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology
Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

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